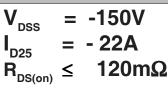


Preliminary Technical Information

PolarP[™] Power MOSFET

IXTC36P15P IXTR36P15P



ISOPLUS247 (IXTR)

E153432

G

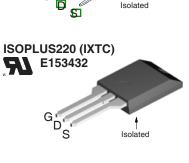
(Electrically Isolated Tab)

P-Channel Enhancement Mode Avalanche Rated



Symbol	Test Conditions	Maximum Ratings			
V _{DSS}	$T_{J} = 25^{\circ}C$ to $175^{\circ}C$	-150	V		
V _{DGR}	$T_{_J}$ = 25°C to 175°C, $R_{_{GS}}$ = 1M Ω	-150	V		
V _{gss}	Continuous	± 20	V		
V_{gSM}	Transient	± 30	V		
I _{D25}	$T_c = 25^{\circ}C$	- 22	A		
I _{DM}	$\rm T_{c}$ = 25°C, Pulse Width Limited by $\rm T_{_{JM}}$	-100	Α		
I _A	$T_{c} = 25^{\circ}C$	- 36	А		
E _{AS}	$T_c = 25^{\circ}C$	1.5	J		
dv/dt	$I_{_{S}} \leq I_{_{DM}}, \ V_{_{DD}} \leq V_{_{DSS}}, \ T_{_{J}} \leq 175^{\circ}C$	10	V/ns		
P _D	$T_{c} = 25^{\circ}C$	150	W		
Tj		- 55 +175	°C		
T		175	°C		
T _{stg}		- 55 +175	°C		
TL	1.6mm (0.062 in.) from Case for 10s	300	°C		
	Plastic Body for 10s	260	°C		
V _{ISOL}	50/60 Hz, RMS, t = 1minute	2500	٧~		
F _c	Mounting Force (ISOPLUS220)	1165 / 2514.6	N/lb		
F _c	Mounting Force (ISOPLUS247)	20120 / 4.527	N/lb		
Weight	ISOPLUS220 ISOPLUS247	2 5	g g		

Symbol (T _J = 25°C, U	cteristio Typ.				
BV _{DSS}	$V_{_{\rm GS}} = 0V, I_{_{\rm D}} = -250 \mu A$	-150			V
V _{GS(th)}	$V_{\text{DS}} = V_{\text{GS}}, I_{\text{D}} = -250 \mu A$	- 3.0		- 5.0	V
I _{GSS}	$V_{\text{GS}} = \pm 20 \text{V}, V_{\text{DS}} = 0 \text{V}$			±100	nA
I _{DSS}	$V_{\text{DS}} = V_{\text{DSS}}, V_{\text{GS}} = 0V$ $T_{\text{J}} = 150^{\circ}\text{C}$			- 10 - 250	
R _{DS(on)}	$V_{gs} = -10V, I_{p} = -18A, Note 1$			120	mΩ



G = Gate D = Drain S = Source

Features

- Silicon Chip on Direct-Copper Bond (DCB) Substrate
- Isolated Mounting Surface
- 2500V~ Electrical Isolation
- Avalanche Rated
- Extended FBSOA
- Fast Intrinsic Diode
- Low $R_{DS(ON)}$ and Q_{G}

Advantages

- Easy to Mount
- Space Savings
- High Power Density

Applications

- High-Side Switching
- Push Pull Amplifiers
- DC Choppers
- Automatic Test Equipment
- Current Regulators
- Battery Charger Applications

Symbol (T ₁ = 25°C	Test Conditions Inless Otherwise Specified)	Characteristic Values Min. Typ. Max.				
g _{fs}		$V_{DS} = -10V, I_{D} = -18A, Note 1$	11	19	S	
C _{iss})			2950	pF	
C _{oss}	}	$V_{_{GS}} = 0V, V_{_{DS}} = -25V, f = 1MHz$		615	pF	
C _{rss}	J			115	pF	
t _{d(on)}	١	Resistive Switching Times		28	ns	
t,		•		37	ns	
t _{d(off)}	Ì	$V_{gs} = -10V, V_{Ds} = 0.5 \bullet V_{Dss}, I_{D} = -18A$		45	ns	
t _f	J	$R_{g} = 5\Omega$ (External)		14	ns	
Q _{g(on)})			55	nC	
Q _{gs}	<pre>}</pre>	$V_{_{ m GS}} = -10V, V_{_{ m DS}} = 0.5 \bullet V_{_{ m DSS}}, I_{_{ m D}} = -18A$		21	nC	
Q _{gd}	J			20	nC	
R _{thJC}					1.00 °C/W	
R _{thCS}				0.15	°C/W	

Source-Drain Diode

LIXYS

Symbol $(T_J = 25^{\circ}C,$	teristic Values Typ. Max.				
I _s	$V_{GS} = 0V$			- 36	A
I _{sm}	Repetitive, Pulse Width Limited by $T_{_{JM}}$			-100	Α
V _{SD}	$I_{_F}$ = -18A, $V_{_{GS}}$ = 0V, Note 1			- 3.0	V
$\left\{ \begin{array}{c} \mathbf{t}_{rr} & \mathbf{Q}_{RM} \end{array} \right\}$	$I_{_{\rm F}}$ = - 25, -di/dt = -100A/µs $V_{_{\rm R}}$ = -100V, $V_{_{\rm GS}}$ = 0V		150 2.0		ns µC

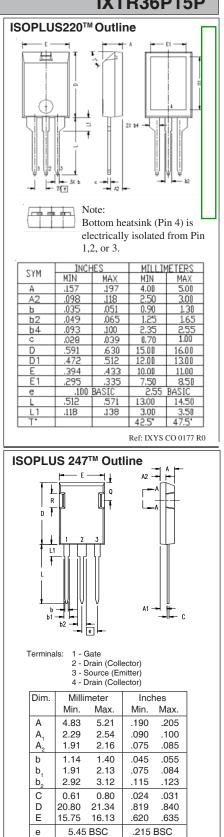
Note 1: Pulse test, $t \le 300\mu s$, duty cycle, $d \le 2\%$.

PRELIMINARY TECHNICAL INFORMATION

The product presented herein is under development. The Technical Specifications offered are derived from data gathered during objective characterizations of preliminary engineering lots; but also may yet contain some information supplied during a pre-production design evaluation. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

IXYS Reserves th	e Right to	Change Limits	Test Conditions	and Dimensions
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IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.											
by one or more of the following U.S. patents: 4	4,850,072		5,063,307	5,381,025	6,162,665 6,259,123 B1 6,306,728 B1	6,534,343	6,683,344 6,710,405 B2 6,710,463	6,759,692	7,005,734 B2 7,063,975 B2 7,071,537	7,157,338B2	



L

L1

Q

R

19.81

3.81

5.59

4.32

20.32

4.32

6.20

4.83

.780

.150

.220 0.244

.170

.800

.170

.190

IXTC36P15P IXTR36P15P



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